

V_{DSS}	-12V
$R_{DS(on)}$ (Max.)	260mΩ
I_D	-1.3A
P_D	1.0W

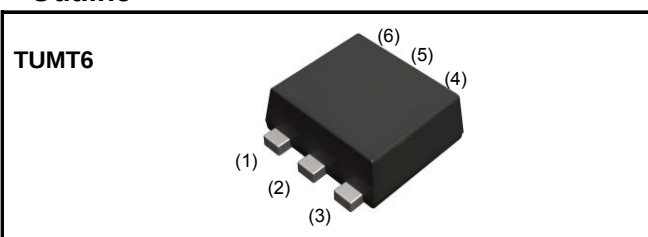
●Features

- 1) Low on - resistance.
- 2) -1.5V Drive.
- 3) Built-in G-S Protection Diode.
- 4) Small Surface Mount Package (TUMT6).
- 5) Pb-free lead plating ; RoHS compliant

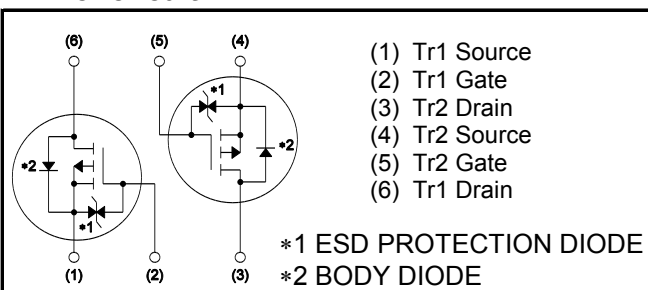
●Application

DC/DC converters

●Outline



●Inner circuit



●Packaging specifications

Type	Packaging	Taping
	Reel size (mm)	180
	Tape width (mm)	8
	Basic ordering unit (pcs)	3,000
	Taping code	TR
	Marking	J11

●Absolute maximum ratings($T_a = 25^\circ\text{C}$) <It is the same ratings for the Tr1 and Tr2>

Parameter	Symbol	Value	Unit
Drain - Source voltage	V_{DSS}	-12	V
Continuous drain current	I_D^{*1}	±1.3	A
Pulsed drain current	$I_{D,pulse}^{*2}$	±5.2	A
Gate - Source voltage	V_{GSS}	±10	V
Power dissipation	P_D^{*3}	1.0	W / total
		0.7	W / element
	P_D^{*4}	0.32	W / total
Junction temperature	T_j	150	°C
Range of storage temperature	T_{stg}	-55 to +150	°C

●Thermal resistance

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
Thermal resistance, junction - ambient	R_{thJA}^{*3}	-	-	125	°C/W
	R_{thJA}^{*4}	-	-	391	°C/W

●Electrical characteristics, unless otherwise specified ($T_a = 25^\circ\text{C}$)

<It is the same characteristics for the Tr1 and Tr2>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -1mA$	-12	-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$	$I_D = -1mA$ referenced to 25°C	-	-17	-	mV/°C
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -12V, V_{GS} = 0V$	-	-	-1	μA
Gate - Source leakage current	I_{GSS}	$V_{GS} = \pm 10V, V_{DS} = 0V$	-	-	±10	μA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = -6V, I_D = 1mA$	-0.3	-	-1.0	V
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{(GS)th}}{\Delta T_j}$	$I_D = -1mA$ referenced to 25°C	-	2.4	-	mV/°C
Static drain - source on - state resistance	$R_{DS(on)}^{*5}$	$V_{GS} = -4.5V, I_D = -1.3A$	-	190	260	mΩ
		$V_{GS} = -2.5V, I_D = -0.6A$	-	280	390	
		$V_{GS} = -1.8V, I_D = -0.6A$	-	400	600	
		$V_{GS} = -1.5V, I_D = -0.2A$	-	530	1060	
		$V_{GS} = -4.5V, I_D = -1.3A, T_j = 125^\circ\text{C}$	-	280	400	
Gate input resistance	R_G	$f = 1MHz, \text{open drain}$	-	28	-	Ω
Transconductance	g_{fs}^{*5}	$V_{DS} = -6V, I_D = -1.3A$	1.4	2.8	-	S

*1 Limited only by maximum temperature allowed.

*2 $P_w \leq 10\mu s$, Duty cycle $\leq 1\%$

*3 Mounted on a ceramic board (30×30×0.8mm)

*4 Mounted on a FR4 (15×20×0.8mm)

*5 Pulsed

●Electrical characteristics($T_a = 25^\circ\text{C}$)

<It is the same characteristics for the Tr1 and Tr2>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Input capacitance	C_{iss}	$V_{GS} = 0V$	-	290	-	pF
Output capacitance	C_{oss}	$V_{DS} = -6V$	-	28	-	
Reverse transfer capacitance	C_{rss}	$f = 1\text{MHz}$	-	21	-	
Turn - on delay time	$t_{d(on)}^{*5}$	$V_{DD} \approx -6V, V_{GS} = -4.5V$	-	8	-	ns
Rise time	t_r^{*5}	$I_D = -0.6A$	-	10	-	
Turn - off delay time	$t_{d(off)}^{*5}$	$R_L = 10\Omega$	-	30	-	
Fall time	t_f^{*5}	$R_G = 10\Omega$	-	9	-	

●Gate Charge characteristics($T_a = 25^\circ\text{C}$)

<It is the same characteristics for the Tr1 and Tr2>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Total gate charge	Q_g^{*5}	$V_{DD} \approx -6V, I_D = -1.3A$ $V_{GS} = -4.5V$	-	2.4	-	nC
Gate - Source charge	Q_{gs}^{*5}		-	0.6	-	
Gate - Drain charge	Q_{gd}^{*5}		-	0.4	-	

●Body diode electrical characteristics (Source-Drain)($T_a = 25^\circ\text{C}$)

<It is the same characteristics for the Tr1 and Tr2>

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Inverse diode continuous, forward current	I_s^{*1}	$T_a = 25^\circ\text{C}$	-	-	-0.5	A
Forward voltage	V_{SD}^{*5}	$V_{GS} = 0V, I_s = -1.3A$	-	-	-1.2	V

●Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

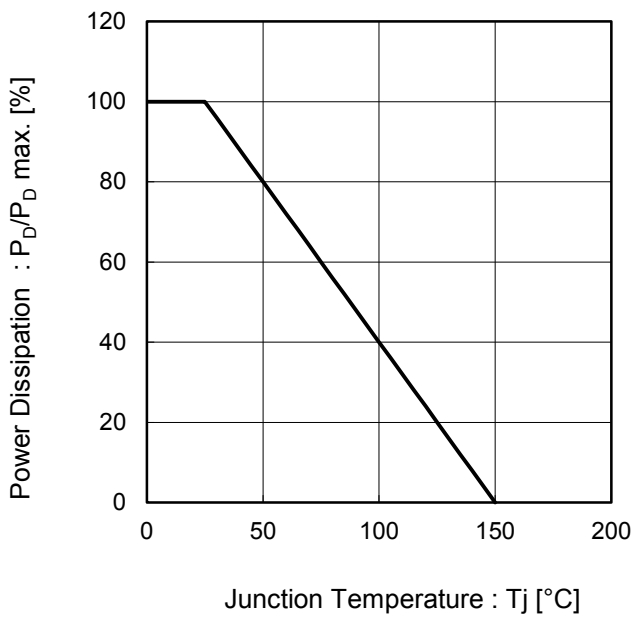


Fig.2 Maximum Safe Operating Area

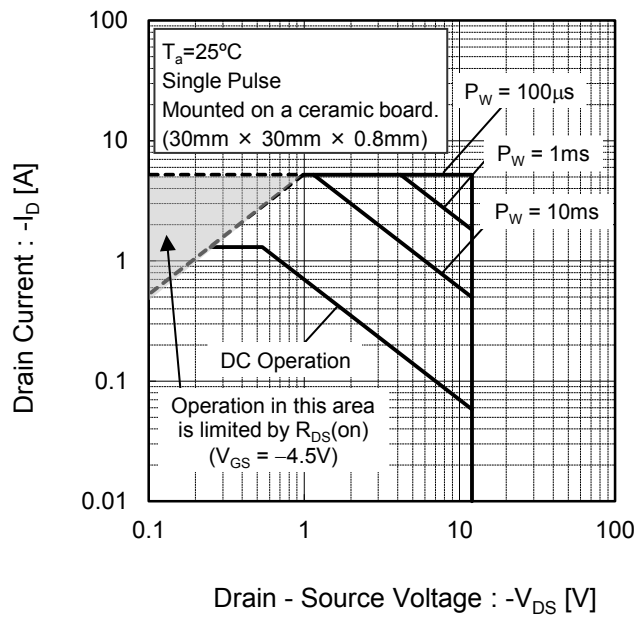


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

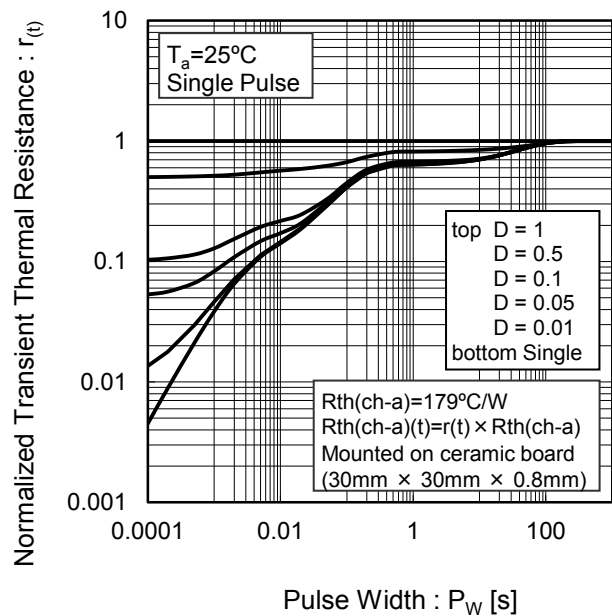
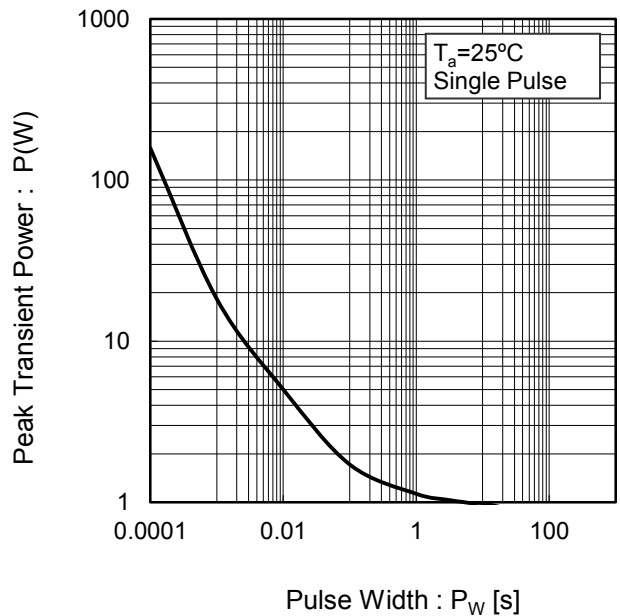


Fig.4 Single Pulse Maximum Power dissipation



●Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)

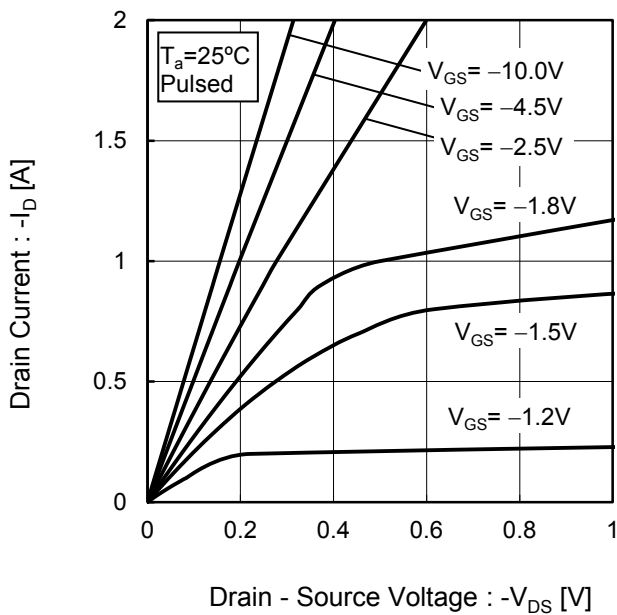


Fig.6 Typical Output Characteristics(II)

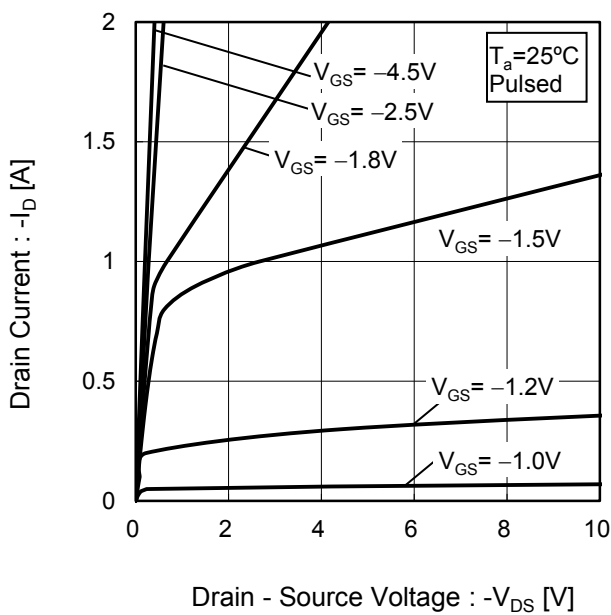


Fig.7 Breakdown Voltage vs. Junction Temperature

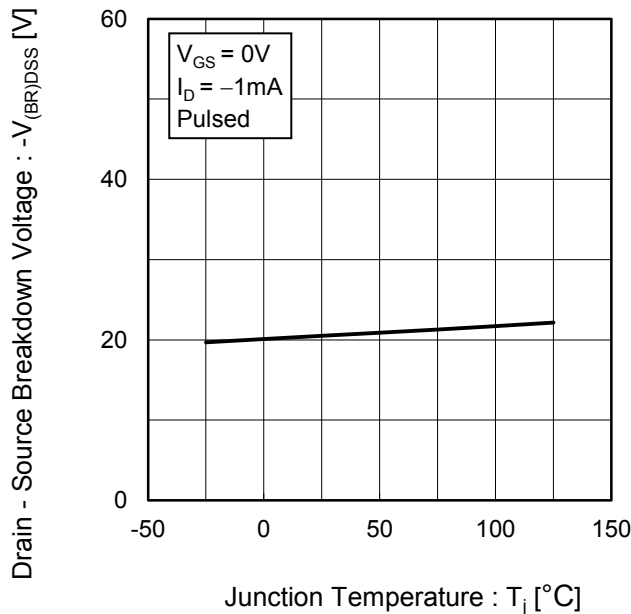
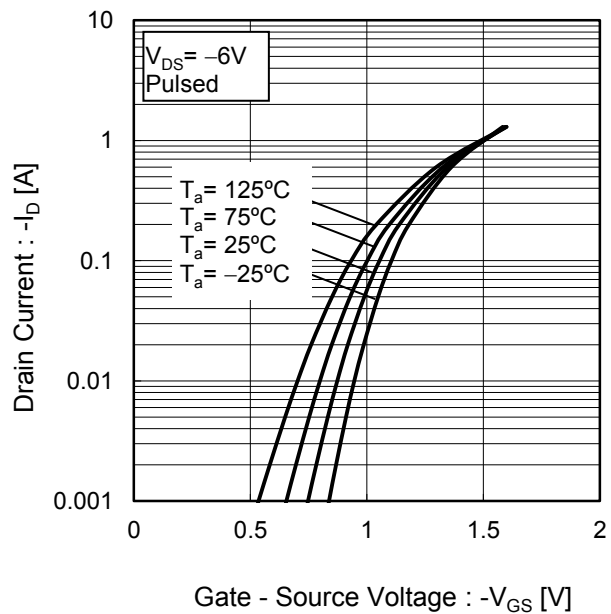


Fig.8 Typical Transfer Characteristics



●Electrical characteristic curves

Fig.9 Gate Threshold Voltage vs. Junction Temperature

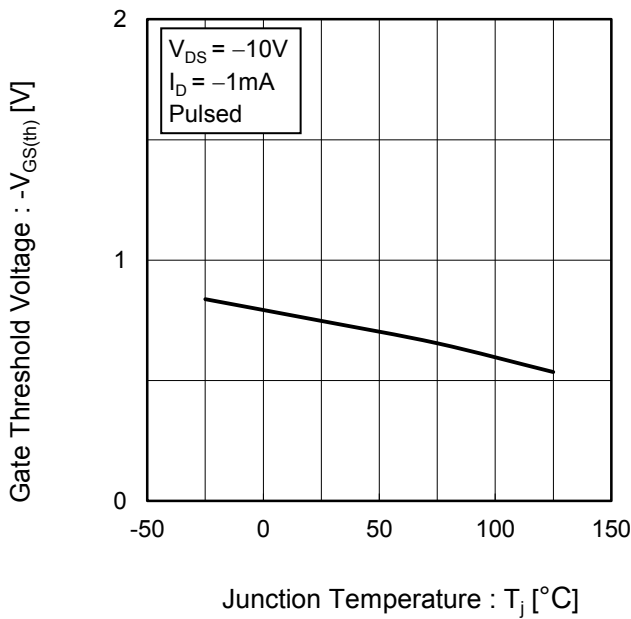


Fig.10 Transconductance vs. Drain Current

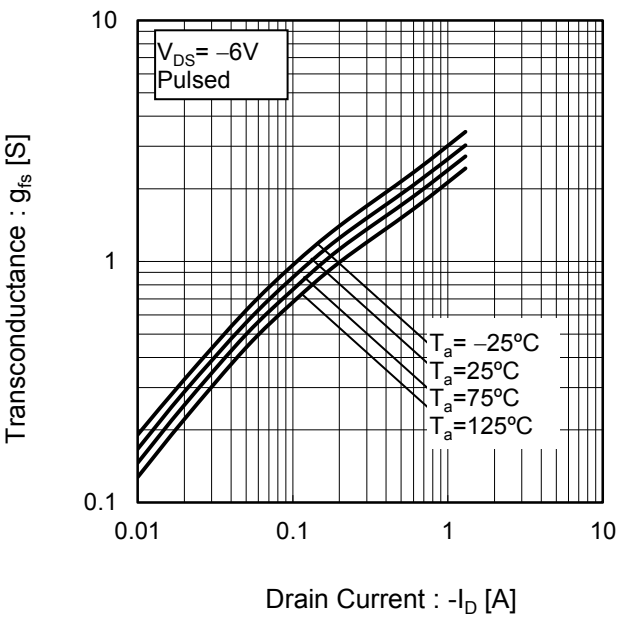


Fig.11 Drain CurrentDerating Curve

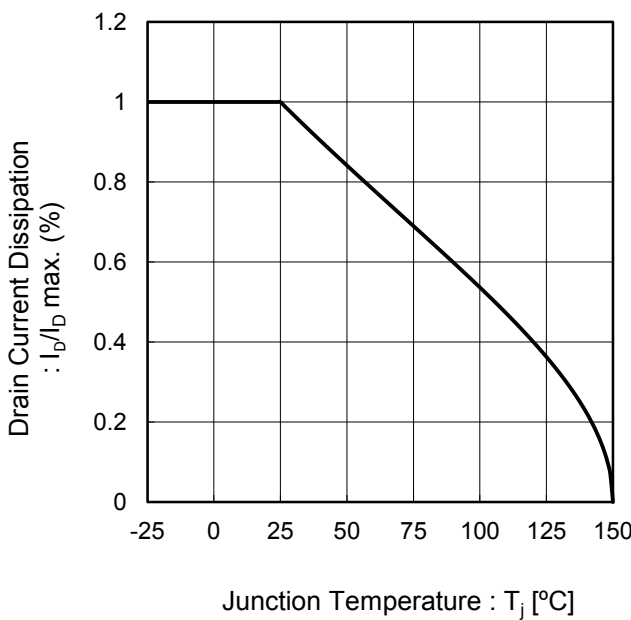
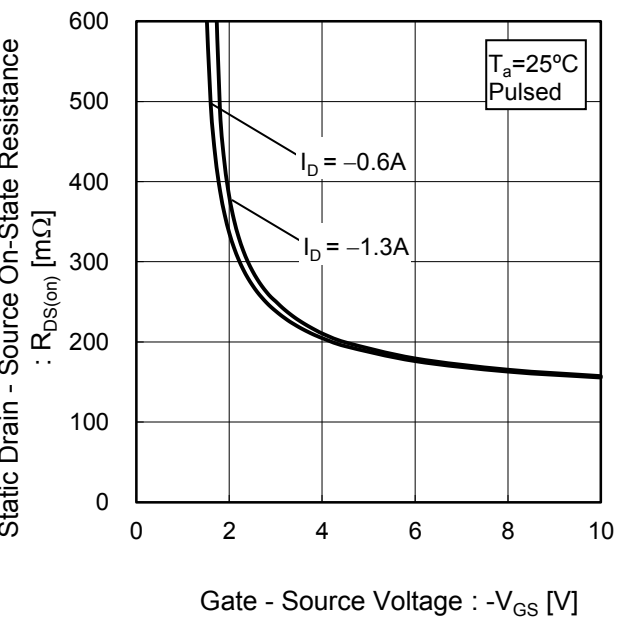


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



●Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)

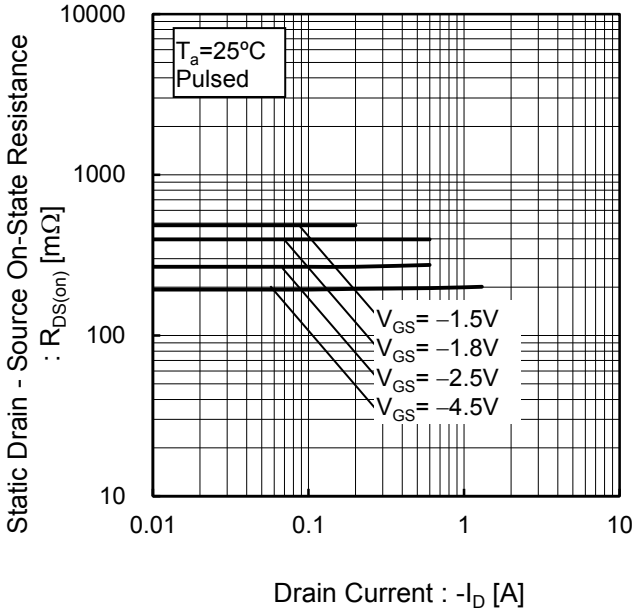
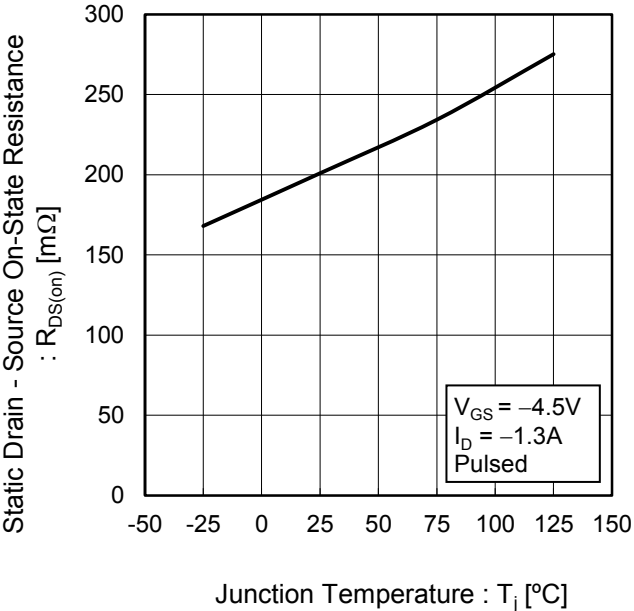


Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature



●Electrical characteristic curves

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current(II)

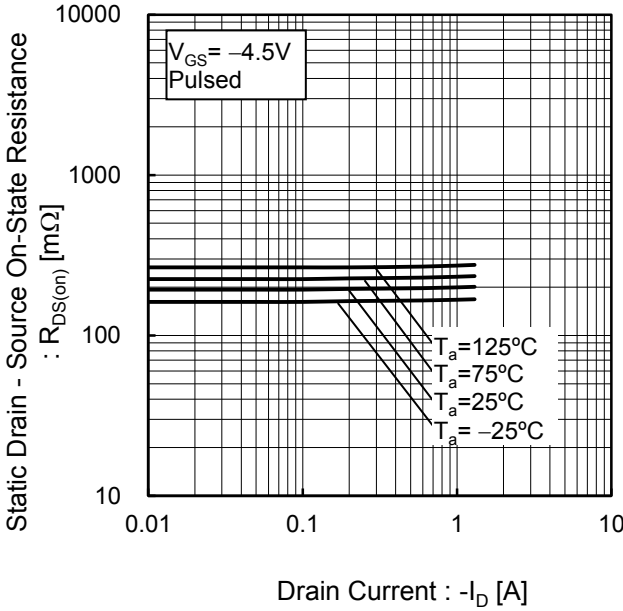


Fig.16 Static Drain-Source On-State Resistance vs. Drain Current(III)

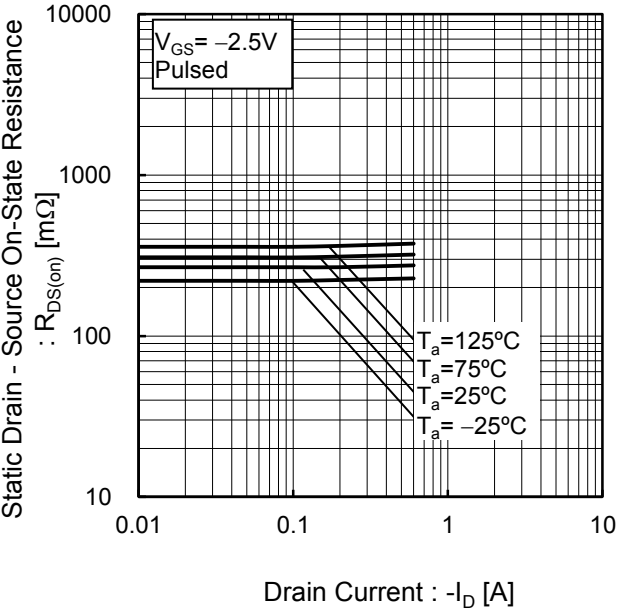


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current(IV)

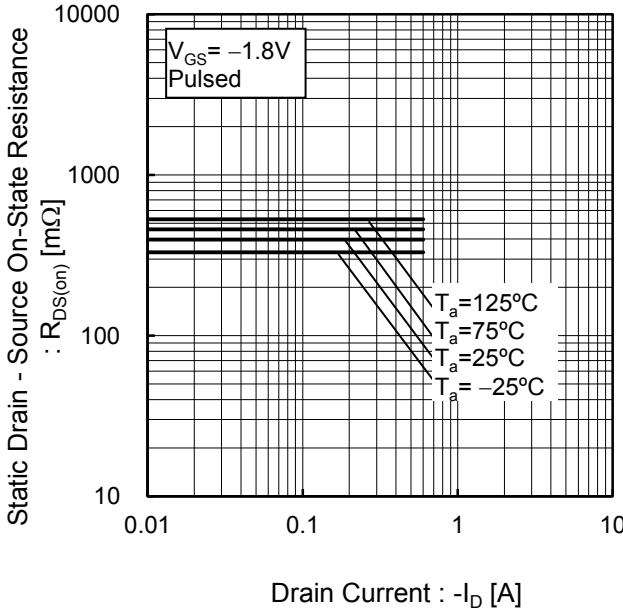
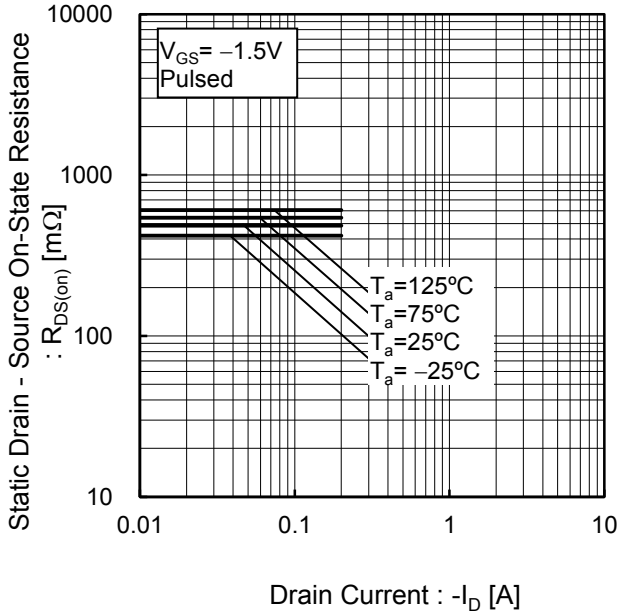


Fig.18 Static Drain - Source On - State Resistance vs. Drain Current(V)



●Electrical characteristic curves

Fig.19 Typical Capacitance vs. Drain - Source Voltage

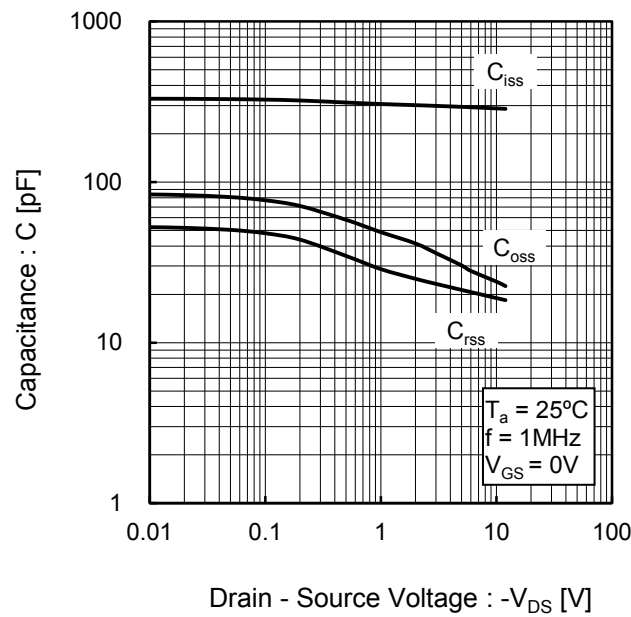


Fig.20 Switching Characteristics

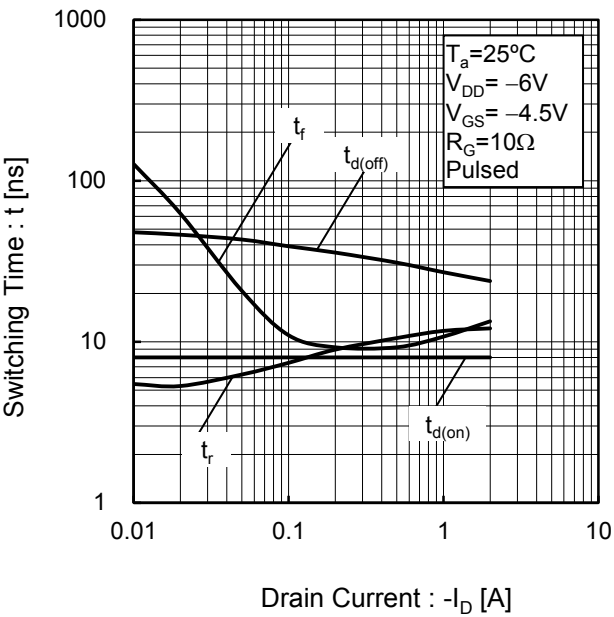


Fig.21 Dynamic Input Characteristics

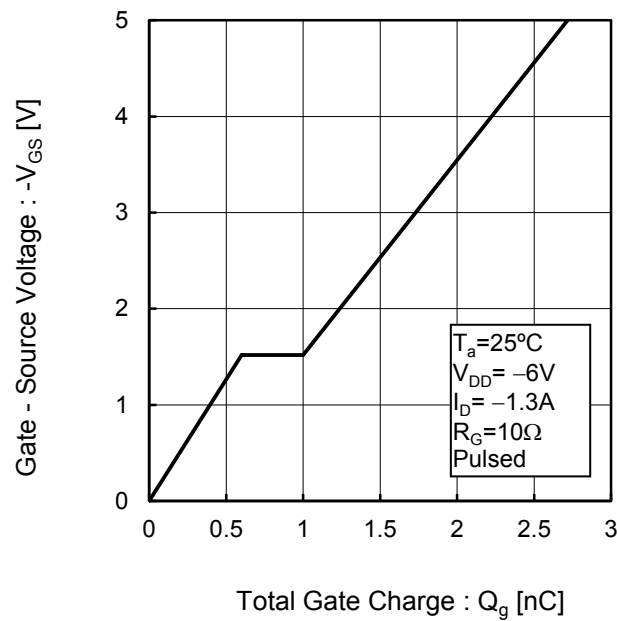
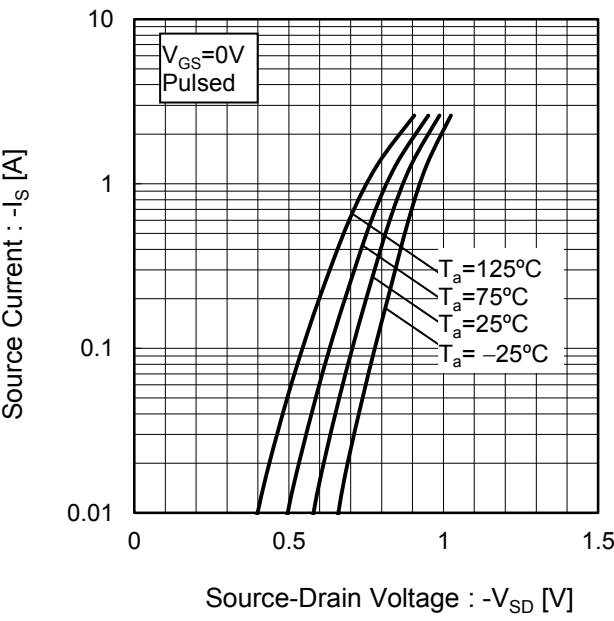


Fig.22 Source Current vs. Source Drain Voltage



●Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

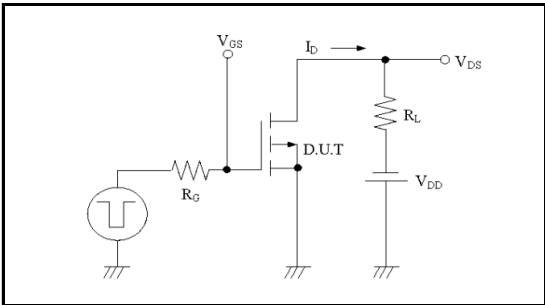


Fig.1-2 Switching Waveforms

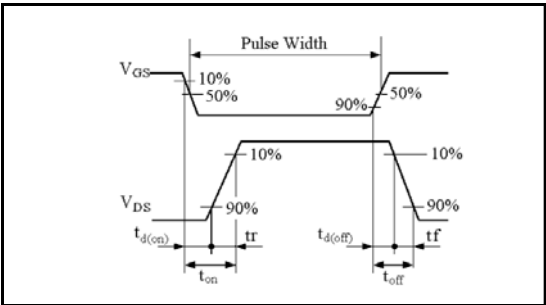


Fig.2-1 Gate Charge Measurement Circuit

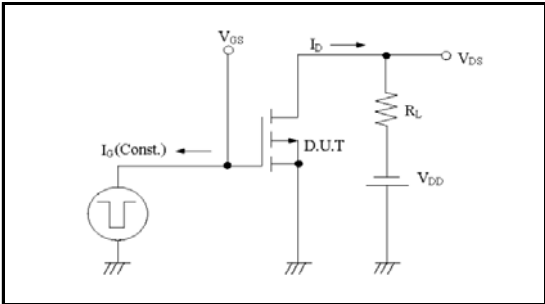
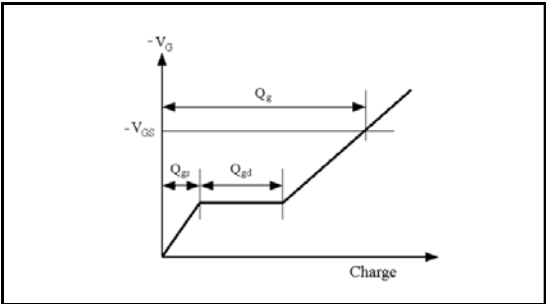
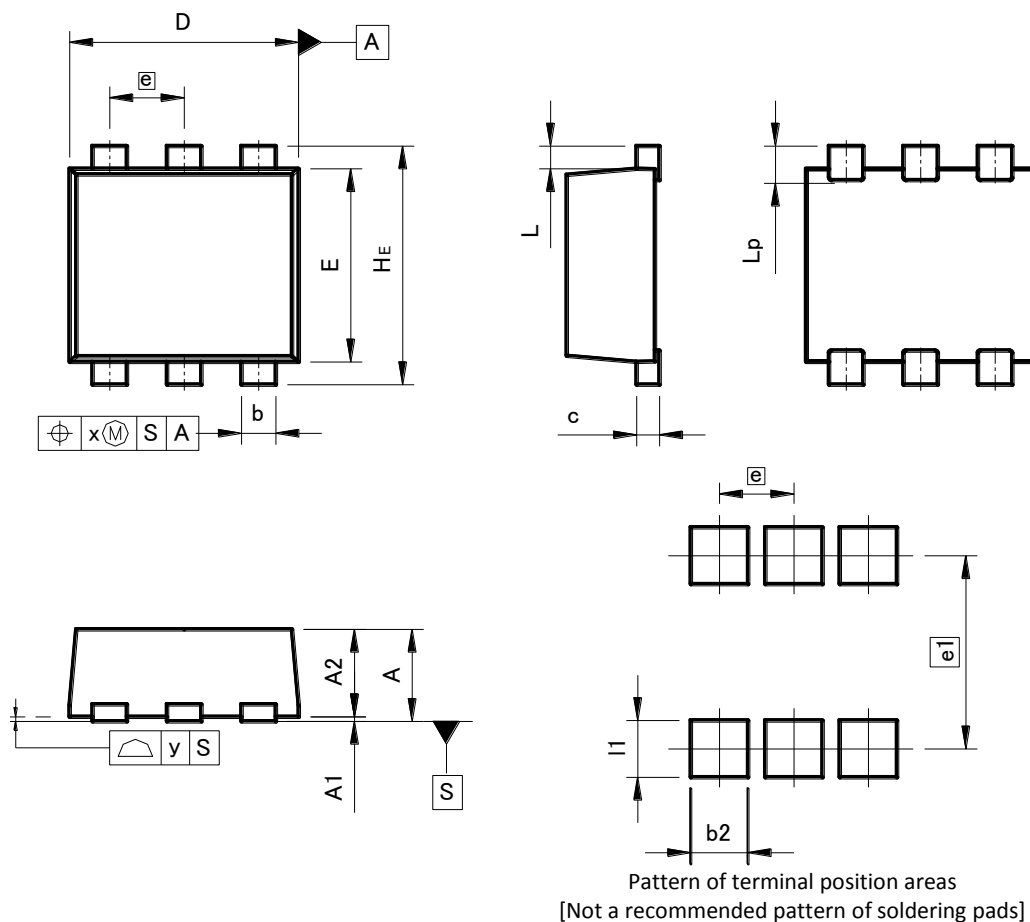


Fig.2-2 Gate Charge Waveform



●Dimensions (Unit : mm)

TUMT6



DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	—	0.85	—	0.033
A1	0.00	0.10	0.000	0.004
A2	0.72	0.82	0.028	0.032
b	0.25	0.40	0.010	0.016
c	0.12	0.22	0.005	0.009
D	1.90	2.10	0.075	0.083
E	1.60	1.80	0.063	0.071
e	0.65		0.026	
HE	2.00	2.20	0.079	0.087
L	0.20		0.008	
Lp	—	0.40	—	0.016
x	—	0.10	—	0.004
y	—	0.10	—	0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	—	0.50	—	0.020
e1	1.70		0.067	
l1	—	0.50	—	0.020

Dimension in mm / inches

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